## NSN 5961-01-227-5784

Yes - demil/mli

**Fiig:** A110a0

Unitized Semiconductor Devices - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-227-5784 **Inclosure Material:** Metal **Overall Length:** 0.840 inches **Overall Height:** 0.910 inches **Overall Width:** 0.619 inches **Mounting Facility Quantity: Component Name And Quantity:** 2 semiconductor device diode **Mounting Method:** Threaded hole **Features Provided:** Hermetically sealed case **Thread Size:** 0.112 inches **Semiconductor Material:** Silicon all semiconductor device diode Voltage Rating In Volts Per Characteristic: 54.0 repetitive peak reverse voltage all semiconductor device diode and 45.0 working peak reverse voltage all semiconductor device diode and 45.0 reverse voltage, instantaneous all semiconductor device diode **Current Rating Per Characteristic:** 75.00 amperes forward current, average all semiconductor device diode **Power Rating Per Characteristic:** 75.0 watts small-signal input power, common-collector absolute all semiconductor device diode **Maximum Operating Tempurature Per Measurement Point:** 175.0 degrees celsius junction **Thread Series Designator: Terminal Type And Quantity:** 4 turret Shelf Life: N/a **Unit Of Measure: Demilitarization:**